NSN 5961-01-087-5889

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View Online at https://aerobasegroup.com/nsn/5961-01-087-5889 **Inclosure Material:** Metal **Overall Length:** 1.125 inches **Overall Diameter:** 1.062 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.219 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 breakover voltage, dc **Current Rating Per Characteristic:** 4.00 milliamperes forward current, average megahertz **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 uninsulated wire lead and 1 threaded stud Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No

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